

L. Number	Hits	Search Text	DB	Time stamp
4	209	("3665241" or "3755704" or "3812559" or "3812559" or "4266233" or "5142184" or "5194780" or "5229331" or "5259799" or "5358908" or "5372973" or "5483067" or "5578896" or "5585301" or "5597444" or "5653619" or "5853492" or "5712534") and planariz\$	USPAT	2003/10/24 11:02
5	5	("3665241" or "3755704" or "3812559" or "3812559" or "4266233" or "5142184" or "5194780" or "5229331" or "5259799" or "5358908" or "5372973" or "5483067" or "5578896" or "5585301" or "5597444" or "5653619" or "5853492" or "5712534") and planariz\$ same porous	USPAT; US-PGPUB	2003/10/24 11:02
-	56	porous adj silicon same dielectric adj constant	USPAT	2002/11/26 19:01
-	1	gate adj insulator same porous and 445/24	USPAT	2002/06/21 09:08
-	3	gate adj insulator same porous and 313/309	USPAT	2002/06/21 09:14
-	105	micron and oxidiz\$ same porous adj silicon	USPAT	2002/06/21 09:47
-	6	445/24 and oxidiz\$ same porous adj silicon not (micron and oxidiz\$ same porous adj silicon)	USPAT	2002/06/21 09:48
-	15	(US-5834845-\$ or US-5527737-\$ or US-6232705-\$ or US-5529524-\$ or US-5981303-\$ or US-5898258-\$ or US-5458518-\$ or US-6333215-\$ or US-6309956-\$ or US-6277765-\$ or US-6255156-\$ or US-6251470-\$ or US-6163066-\$ or US-6156374-\$ or US-6072227-\$).did.	USPAT	2002/06/21 16:16
-	15	(US-5834845-\$ or US-5527737-\$ or US-6232705-\$ or US-5529524-\$ or US-5981303-\$ or US-5898258-\$ or US-5458518-\$ or US-6333215-\$ or US-6309956-\$ or US-6277765-\$ or US-6255156-\$ or US-6251470-\$ or US-6163066-\$ or US-6156374-\$ or US-6072227-\$).did.	USPAT	2002/06/21 17:03
-	7	((US-5834845-\$ or US-5527737-\$ or US-6232705-\$ or US-5529524-\$ or US-5981303-\$ or US-5898258-\$ or US-5458518-\$ or US-6333215-\$ or US-6309956-\$ or US-6277765-\$ or US-6255156-\$ or US-6251470-\$ or US-6163066-\$ or US-6156374-\$ or US-6072227-\$).did.) and anodiz\$	USPAT	2002/06/21 16:39
-	1	((US-5834845-\$ or US-5527737-\$ or US-6232705-\$ or US-5529524-\$ or US-5981303-\$ or US-5898258-\$ or US-5458518-\$ or US-6333215-\$ or US-6309956-\$ or US-6277765-\$ or US-6255156-\$ or US-6251470-\$ or US-6163066-\$ or US-6156374-\$ or US-6072227-\$).did.) and thermal\$ adj oxidiz\$	USPAT	2002/06/21 16:35
-	0	(US-5834845-\$ or US-5527737-\$ or US-6232705-\$ or US-5529524-\$ or US-5981303-\$ or US-5898258-\$ or US-5458518-\$ or US-6333215-\$ or US-6309956-\$ or US-6277765-\$ or US-6255156-\$ or US-6251470-\$ or US-6163066-\$ or US-6156374-\$ or US-6072227-\$).did. and (void or cavity) same percent same anodiz\$	USPAT	2002/06/21 17:05
-	9	(void or cavity) same percent and silicon with anodiz\$	USPAT	2002/06/21 17:07
-	9	(void or cavity) same percent and silicon with anodiz\$	USPAT	2002/06/21 17:10
-	0	volumn same percent and silicon with anodiz\$	USPAT	2002/06/21 17:11
-	0	volumn same percent same silicon near4 porous	USPAT	2002/06/21 17:12
-	0	volumn same percent and silicon near4 porous	USPAT	2002/06/21 17:13
-	87	percent same "75" and silicon near4 porous	USPAT	2002/06/21 17:27
-	91	silicon same anodiz\$ same porosity	USPAT	2002/06/21 18:07
-	1	silicon same anodiz\$ same column\$ near3 structure	USPAT	2002/06/21 18:10
-	0	silicon same anodiz\$ same column\$ near3 microstructure	USPAT	2002/06/21 18:11
-	26	silicon same anodiz\$ same microstructure	USPAT	2002/06/21 18:32
-	5	silicon near3 porous and dielectric near4 1.6	USPAT	2002/06/21 18:33
-	33	445/24 and low adj dielectric	USPAT	2002/06/21 18:54
-	2	2593953.pn.	DERWENT	2002/06/23 20:06
-	0	field adj emitters same silicon adj monoxide	USPAT	2002/06/23 21:07
-	4	field adj emitters and silicon adj monoxide	USPAT	2002/06/23 21:12
-	1	(field adj emitters and silicon adj monoxide) and porous same oxidiz\$	USPAT	2002/06/23 21:15
-	3	(field adj emitters and silicon adj monoxide) not ((field adj emitters and silicon adj monoxide) and porous same oxidiz\$)	USPAT	2002/06/23 21:16
-	1	5529524.pn. and planariz\$	USPAT	2002/11/26 19:08
-	1	5663608.pn. and planariz\$	USPAT	2002/11/26 19:09